

FORM PTO-1390

U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE

ATTORNEY'S DOCKET NUMBER

**TRANSMITTAL LETTER TO THE UNITED STATES
DESIGNATED/ELECTED OFFICE (DO/EO/US)
CONCERNING A FILING UNDER 35 U.S.C. 371**

2134-022 **10/088591**

U.S. APPLICATION NO. (if known, see 37 CFR 1.5)

10/088591

INTERNATIONAL APPLICATION NO.

PCT/DE00/03231

INTERNATIONAL FILING DATE

September 18, 2000

PRIORITY DATE CLAIMED

September 21, 1999

TITLE OF INVENTION

**MEASURING PROBE FOR MEASURING HIGH FREQUENCIES AND METHOD OF
PRODUCING THE SAME**

APPLICANT(S) FOR DO/EO/US

Michael WOLLITZER

Applicant herewith submits to the United States Designated/Elected Office (DO/EO/US) the following items and other information:

1. ☒ This is a **FIRST** submission of items concerning a filing under 35 U.S.C. 371.
2. ☐ This is a **SECOND** or **SUBSEQUENT** submission of items concerning a filing under 35 U.S.C. 371.
3. ☐ This express request to begin national examination procedures (35 U.S.C. 371(f)) at any time rather than delay examination until the expiration of the applicable time limit set in 35 U.S.C. 371(b) and PCT Articles 22 and 39(1).
4. ☒ A proper Demand for International Preliminary Examination was made by the 19th month from the earliest claimed priority date.
5. ☒ A copy of the International Application as filed (35 U.S.C. 371(c)(2))
 - a. ☒ is transmitted herewith (required only if not transmitted by the International Bureau).
 - b. ☐ has been transmitted by the International Bureau.
 - c. ☐ is not required, as the application was filed in the United States Receiving Office (RO/US)
6. ☒ A English translation of the International Application into English (35 U.S.C. 371(c)(2)).
 - a. ☒ is attached hereto
 - b. ☐ has been previously submitted under 35 U.S.C. 154 371 (c)(2)
7. ☒ Amendments to the claims of the International Application under PCT Article 19 (35 U.S.C. 371(c)(3))
 - a. ☒ are transmitted herewith (required only if not transmitted by the International Bureau).
 - b. ☐ have been transmitted by the International Bureau.
 - c. ☐ have not been made; however, the time limit for making such amendment has NOT expired.
 - d. ☐ have not been made and will not be made.
8. ☒ A English translation of the amendments to the claims under PCT Article 19 (35 U.S.C. 371(c)(3)).
9. ☐ An oath or declaration of the inventor(s) (35 U.S.C. 371(c)(4)).
10. ☐ A English translation of the annexes to the International Preliminary Examination Report under PCT Article 36 (35 U.S.C. 371(c)(5)).

Items 11. to 20. below concern other document(s) or information included:

11. ☒ An Information Disclosure Statement under 37 CFR 1.97 and 1.98.
12. ☐ An assignment document for recording. A separate cover sheet in compliance with 37 CFR 3.28 and 3.31 is included.
13. ☒ A FIRST preliminary amendment.
14. ☐ A SECOND or SUBSEQUENT preliminary amendment.
15. ☐ A substitute specification.
16. ☐ A change of power of attorney and/or address letter.
17. ☐ A computer-readable form of the sequence listing in accordance with PCT Rule 13ter.2 and 35 U.S.C. 1 821-1.825
18. ☐ A second copy of the published international application under 35 U.S.C. 154(d)(4)
19. ☐ A second copy of the English language translation of the international application under 35 U.S.C. 154(d)(4)
20. ☐ Other items or information

a.

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APPLIC NO. (if known, see 37 CFR 1.5)		INTERNATIONAL APPLICATION NO.	ATTORNEY'S DOCKET NUMBER
10/000000		PCT/DE00/03231	2134-022

21. <input checked="" type="checkbox"/> The following fees are submitted				CALCULATIONS		PTO USE ONLY		
Basic National Fee (37 CFR 1.492(a)(1)-(5)): Neither international preliminary examination fee (37 CFR 1.482) nor international search fee (37 CFR 1.445(a)(2)) paid to USPTO and International Search Report not prepared by the EPO or JPO \$ 1040.00 International Search fee (37 CFR 1.482) not paid to USPTO but International Search Report prepared by the EPO and JPO \$ 890.00 International preliminary examination fee (37 CFR 1.482) not paid to USPTO but international search fee (37 CFR 1.445(a)(2)) paid to USPTO \$ 740.00 International preliminary examination fee paid to USPTO (37 CFR 1.482) but all claims did not satisfy provisions of PCT Article 33(1)-(4) \$ 710.00 International preliminary examination fee paid to USPTO (37 CFR 1.482) And all claims satisfied provisions of PCT Article 33(2)-(4) \$ 100.00								
				ENTER APPROPRIATE BASIC FEE AMOUNT =		\$	890.00	
				Surcharge of \$130.00 for furnishing the oath or declaration later than <input type="checkbox"/> 20 <input checked="" type="checkbox"/> 30 months from the earliest claimed priority date (37 CFR 1.492(e)).		\$	130.00	
CLAIMS	NUMBER FILED	NUMBER EXTRA	RATE					
Total Claims	8 - 20 =	0	X \$18.00	\$	0.00			
Independent Claims	1 - 3 =	0	X \$84.00	\$	0.00			
Multiple dependent claim(s) (if applicable)			+ \$280.00	\$	0.00			
TOTAL OF ABOVE CALCULATIONS =				\$	1,020.00			
<input type="checkbox"/> Applicant claims small entity status. See 37 CFR 1.27. The fees indicated above are reduced by 1/2.				\$	0.00			
SUBTOTAL =				\$	1,020.00			
Processing fee of \$130.00 for furnishing the English translation later than the <input type="checkbox"/> 20 <input type="checkbox"/> 30 months from the earliest claimed priority date (37 CFR 1.492(f)).				\$	0.00			
TOTAL NATIONAL FEE =				\$	1,020.00			
Fee for recording the enclosed assignment (37 CFR 1.21(h)). The assignment must be accompanied by an appropriate cover sheet (37 CFR 3.28, 3.31). \$40.00 per property				\$	0.00			
TOTAL FEES ENCLOSED =				\$	1,020.00			
				Amount to be:	\$			
				refunded				
				charged	\$			

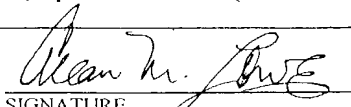
a. ☐ A check in the amount of \$ XXX XX to cover the above fees is enclosed

b. ☐ Please charge my Deposit Account No. XXX in the amount of \$ XXX to cover the above fees. A duplicate copy of this sheet is enclosed.

c. ☒ The Commissioner is hereby authorized to charge any additional fees which may be required, or credit any overpayment to Deposit Account No. 07-1337. A duplicate copy of this sheet is enclosed.

c. ☒ Fees are to be charged to a credit card. **WARNING:** information on this form may be public. Credit card information should not be included on this form. Provide credit card information and authorization on PTO-2038

NOTE: Where an appropriate time limit under 37 CFR 1.494 or 1.495 has not been met, a petition to revive (37 CFR 1.137(a) or (b)) must be filed and granted to restore the application to pending status.

SEND ALL CORRESPONDENCE TO: LOWE HAUPTMAN GILMAN & BERNER, LLP Customer No. 22429 1700 Diagonal Road, Suite 310 Alexandria, VA 22314 (703) 684-1111	 SIGNATURE Allan M. Lowe NAME 19,641 REGISTRATION NUMBER
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JC10 Rec'd PCT/PTO 21 MAR 2002

Docket No.: 2134-022PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of :
Michael WOLLITZER :
Serial No. n/a : Group Art Unit:
Filed: Herewith : Examiner:
For: MEASURING PROBE FOR MEASURING HIGH FREQUENCIES AND METHOD
OF PRODUCING THE SAME

PRELIMINARY AMENDMENT

Assistant Commissioner for Patents
Washington, D. C. 20231

Sir:

Prior to examination on the merits, please amend the
referenced application as follows:

IN THE CLAIMS:

Please amend claims 1-6 as follows:

1. (amended) Measuring probe for measuring high frequencies,
comprising a contact end for contacting planar structures and a co-
axial cable end for connection to a co-axial cable; a co-planar
conductor structure having at least two conductors arranged between
the contact end and the co-axial cable end; a dielectric for
mounting the co-planar conductor structure, the dielectric being
arranged on the co-planar conductor structure; the dielectric being
arranged on at least one side of the co-planar conductor structure
in a central section between, and spaced, in the direction of
propagation, from the co-axial cable end and the contact end, each

Serial No. n/a

6. (amended) Measuring probe according to claim 1, further including a planar circuit arranged at the co-axial cable end.

Please add new claims 7 and 8 as follows:

--7. (new) The measuring probe of claim 6 wherein the planar circuit includes at least one active circuit element.

--8. (new) The measuring probe of claim 1 wherein the dielectric is on both sides of the co-planar conductor structure.--

Serial No. n/a

MARKED-UP VERSION SHOWING CHANGES:

1. (amended) Measuring probe [(100, 200, 300)] for measuring high frequencies, [having] comprising a contact end [(20)] for contacting planar structures and a co-axial cable end [(18)] for connection to a co-axial cable [(22),] ; a co-planar conductor structure [(10)] having at least two conductors [(12, 14) being] arranged between the contact end [(20)] and the co-axial cable end ; [(18) and] a dielectric [(28) acting as a mounting for] for mounting the co-planar conductor structure [(10)], the dielectric being arranged on the co-planar conductor structure [(10), characterised in that] ; the dielectric [(28) is] being arranged on at least one side[, and in particular on both sides,] of the co-planar conductor structure [(10)] in a central section between, and spaced, [away from] in the direction of propagation, from the co-axial cable end [(19)] and the contact end [(20)], [in such a way that] each conductor [(12, 14)] in the co-planar conductor structure [(10) is] being formed to be individually free in space and resilient in relation to the dielectric [(28) acting as its mounting], 'a respective gap [(16)] being formed between each pair of conductors [(12, 14)] in the co-planar conductor structure [(10)] from the co-axial cable end [(18)] to the contact end [(20)] in such a way that a constant characteristic impedance is obtained from the co-axial cable end [(18)] to the contact end [(20)].

2. (amended) Measuring probe [(100, 200, 300)] according to claim 1, [characterised in that] wherein the respective gap [(16)] is [made] wider in the region of the dielectric [(28)] than in the region of the co-planar conductor structure [(10)] where there is no dielectric [(28)].

3. (amended) Measuring probe [(100, 200, 300)] according to

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claim 1, [characterised in that] wherein the dielectric [is in the form of] includes at least one block of quartz [(28)].

4. (amended) Measuring probe [(100, 200, 300)] according to claim 1, [characterised in that] wherein the dielectric [(28)] has, on a side where it is connected to the co-planar conductor structure [(10)], a metal coating [which] having substantially [coincides in] the same shape [with] as the [latter] co-planar conductor structure.

5. (amended) Measuring probe [(200)] according to claim 1, [characterised in that] wherein the dielectric [(28)] is metallised over its full area on a side remote from the co-planar conductor structure.

6. (amended) Measuring probe according to claim 1, [characterised in that] further including a planar circuit [and in particular an electrical or electronic, i.e. active, circuit or at least one active circuit element is] arranged at the co-axial cable end [(18)].

Measuring probe for measuring high frequencies and method of
producing said probe

The invention relates to a measuring probe for measuring
5 high frequencies as detailed in the preamble of claim 1, having
a contact end for contacting planar structures and a co-axial
cable end for connection to a co-axial cable, a co-planar
conductor structure having at least two conductors being
arranged between the contacting end and the co-axial cable end.
10 The invention further relates to a method as detailed in the
preamble of claim 8 for producing a measuring probe for
measuring high frequencies, having a contact end for contacting
planar structures and an co-axial cable end for connection to a
co-axial cable, a co-planar conductor structure having at least
15 two conductors being arranged between the contacting end and the
co-axial cable end.

To test electronic circuits produced on wafers for example
for their ability to operate and their electrical
characteristics, use is usually made of measuring probes which
20 are applied mechanically to appropriate contact points on the
electronic circuit to be tested. Electronic circuits of this
kind which need to be tested are increasingly ones which
generate or process high-frequency signals, which means that for
the measuring probe there is an impedance of which due note
25 needs to be taken. In other words, the measuring probe needs to
have an impedance matched to the contact with the electrical
circuit to be tested as otherwise, if there are mismatches,
there will, as is generally known, be corresponding reflections
which will have an unwanted effect on any measurement made or
30 will make measurement totally impossible. There should not even
be any change in impedance over the measuring probe itself
because jumps in impedance of this kind also cause corresponding
points of reflection.

This object is achieved by a measuring probe of the above kind having the features detailed in the characterising clause of claim 1 and by a method of the above kind having the features

detailed in the characterising clause of claim 8. Advantageous embodiments of the invention are detailed in the independent claims in the respective cases.

In a measuring probe of the above kind, provision is made in accordance with the invention for a dielectric serving as a mounting for the co-planar conductor structure to be arranged on at least one side and in particular on both sides of said structure over a predetermined section thereof between the co-axial cable end and the contact end, the measuring probe being so formed between the dielectric and the contact end that the conductors in the co-planar conductor structure are arranged to be free in space and resilient in relation to the dielectric acting as their mounting.

This has the advantage that it provides an inexpensive and accurate measuring probe which can even be produced in volume and whose impedance is controlled, thus giving low reflections when contact is made with the planar structure for measuring purposes. The arrangement according to the invention is notable for operating frequencies of up to 40 to 60 GHz, with impedance being substantially free of dispersion, i.e. independent of the operating frequency, over the whole of the co-planar conductor structure due to the design according to the invention. The freely resilient arrangement of the conductors in the co-planar conductor structure between the dielectric and the co-axial cable end ensures that there is contact of a high standard between all the conductors in the co-planar conductor structure and the corresponding contact points on a device to be tested, the standard of the contact not being affected by the measuring probe being tilted when it is applied to the contact points.

30 To ensure contact characteristic impedance over the measuring probe, a respective gap is suitably formed between each pair of conductors in the co-planar conductor structure from the co-axial cable end to the contact end, the respective

gap being in particular made wider in the region of the dielectric than in the region of the co-planar conductor structure where there is no dielectric.

In a preferred embodiment, the dielectric is in the form of
5 at least one block of quartz.

To provide a secure connection between the co-planar conductor structure and the block of dielectric, the latter has, on a side where it is connected to the co-planar structure, a metal coating which substantially coincides in shape with the latter.

To suppress higher-order modes above the desired operating frequency, the dielectric is metallised over its full area on a side remote from the co-planar conductor structure. This also produces a closed, shielded structure in the region of the

For certain applications, a planar circuit and in particular an electrical or electronic i.e. active circuit or at least one active circuit element is arranged at the co-axial cable end. This puts the additional circuit or the additional circuit element in the immediate vicinity of contacts between the measuring probe and a circuit to be tested at the contact end of the measuring probe.

In a method of the above kind, provision is made in accordance with the invention for the conductors of the coplanar conductor structure to be produced by a lithographic electrofabrication process

This has the advantage that a measuring probe of small dimensions with a precisely predetermined characteristic impedance which thus shows low reflection of high frequencies and hence has a high bandwidth can be produced in a simple, inexpensive and, for volume production, repeatable manner.

For volume production, at least one and in particular more than one co-planar conductor structure is produced on a silicon

wafer by a photolithographic process.

Mechanical strength for the conductors of a co-planar wave-transmitting line up to the time of final assembly without any complicated lining-up of the conductors is achieved by producing the co-planar conductor structure by the lithographic electrofabrication process in such a way that the conductors are connected together at one end.

In a preferred embodiment, the method comprises the following steps:

- (a) vapour deposition of a layer of metal on a silicon wafer,
- (b) application of a light-sensitive resist,
- (c) exposure of the light-sensitive resist through a mask which is substantially a negative of the structure of at least one co-planar conductor structure to be produced,
- (d) developing the resist to give a structure having depressions corresponding to the structure of the co-planar conductor structures to be produced,
- (e) filling the depressions with an electrically conductive material by electroplating,
- (f) removing the layer of metal and detaching the co-planar conductor structure from the wafer,
- (g) connecting individual co-planar conductor structures on one or both sides to a carrier member between the co-axial cable end and the contact end and
- (h) connecting the co-planar conductor structure to the co-axial cable.

The layer of metal in step (a) comprises for example titanium, silver, chromium and/or gold and as one option the electrically conductive material in step (e) may be nickel. The carrier member in step (g) is for example a dielectric and in particular a block of quartz. Advantageously, the co-planar wave-transmitting line and the carrier member or members are

also mounted in a housing in a subsequent step. In the region of the quartz block this produces a tunnel giving all-round shielding.

To cause the conductors in the co-planar conductor structure to be fixed in position in a suitable manner, in steps (a) to (e) each co-planar conductor structure is produced with a bridge which connects all the conductors in a co-planar conductor structure together, particularly at the co-axial cable end. This bridge is advantageously removed after the fitting of the carrier member or members or before the connection to the co-axial cable.

For even greater strength, the bridge also comprises a frame which surrounds the co-planar conductor structure.

The invention will be explained in detail below by reference to the drawings. In the drawings:

Fig.1 is a perspective view of a first preferred embodiment of a measuring probe according to the invention,

Fig.2 is a perspective view of a second preferred embodiment of a measuring probe according to the invention,

Fig.3 is a plan view of a third preferred embodiment of a measuring probe according to the invention,

Figs.4 to 7 show successive steps in a method according to the invention, and

Fig.8 is an S parameter plot from a simulation calculation for a measuring probe according to the invention.

The first preferred embodiment of a measuring probe according to the invention which is shown in Fig.1 comprises a co-planar conductor structure 10 having a signal conductor 12 in the centre and two ground conductors 14 arranged in co-planar positions adjacent to the signal conductor 12. A predetermined gap 16 is formed between signal conductor 12 and a given ground conductor 14. The co-planar conductor structure 10 extends from a co-axial cable end 18 to a contact end 20 and the gap 16 is

formed over the entire length of the co-planar conductor structure 10 in such a way as to produce a constant predetermined characteristic impedance. At the co-axial cable end 18, the co-planar conductor structure 18 is connected to a co-axial cable 22, with the signal conductor 12 making contact with a centre conductor 24 and the ground conductors 14 with an outer conductor 26 of the co-axial cable.

In a central section between the co-axial cable end 18 and the contact end 20, there is arranged on the two sides of the co-planar conductor structure 10 a dielectric in the form of respective blocks of quartz 28. The two quartz blocks 28 and the co-planar conductor structure 10 are placed one on top of the other in a sandwich-like structure. The quartz blocks 28 are securely connected to the co-planar conductor structure 10 and each carry on their side adjacent the co-planar conductor structure 10 metallising which substantially matches the shape of the co-planar conductor structure 10 in the region of the quartz blocks 28. What is obtained in this way is a particularly firm and close connection between the quartz blocks 28 and the conductors 12, 14 of the co-planar conductor structure 10. Because of the electromagnetic relationship with the dielectric 28, the gap 16 is widened in the region of the quartz blocks 28 thus giving, overall, a constant characteristic impedance over the entire co-planar conductor structure 10 from the co-axial cable end 18 to the contact end. The respective metallisings on the two quartz blocks 28 are advantageously connected together electrically by means of a suitable fitting technique. This gives a ground plane which is identical for both sides of the quartz blocks and a corresponding identical shielding action.

As is immediately evident from Fig.1, conductors 12, 14 are arranged to be free in space in a region 29 between the quartz blocks 28 acting as mountings and the contact end 20, thus allowing each conductor to be individually resilient relative to

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Something particularly notable about the method according to the invention is that in no way is there a need for the individual conductors 12, 14 in the co-planar conductor

Something particularly notable about the method according to the invention is that in no way is there a need for the individual conductors 12, 14 in the co-planar conductor

structure 10 to be aligned in relation to one another at the time of fitting. The arrangement of conductors 12, 14 relative to one another is preset and fixed from the start of the production process to the end. This gets rid of any tolerances which might arise if the individual conductors 12, 14 were positioned mechanically during the production process.

The measuring probe according to the invention has a surprising good frequency response, as can be seen from Fig.8. Fig.8 shows an S parameter plot from a simulation calculation for a measuring probe according to the invention. What is plotted in this case is a frequency in GHz along the horizontal axis 46 and an S parameter in dB along the vertical axis 48. As is immediately apparent from the graph shown in Fig.8, this model calculation shows that the measuring probe according to the invention can be used at frequencies of up to 60 GHz. And this is true with, at the same time, the possibility of its being produced in volume at low cost with a low scrap rate.

Claims

1. Measuring probe (100, 200, 300) for measuring high frequencies, having a contact end (20) for contacting planar structures and a co-axial cable end (18) for connection to a co-axial cable (22), a co-planar conductor structure (10) having at least two conductors (12, 14) being arranged between the contact end (20) and the co-axial cable end (18) and a dielectric (28) acting as a mounting for the co-planar conductor structure (10) being arranged on the co-planar conductor structure (10), characterised in that the dielectric (28) is arranged on at least one side, and in particular on both sides, of the co-planar conductor structure (10) in a central section between, and spaced away from in the direction of propagation, the co-axial cable end (19) and the contact end (20), in such a way that each conductor (12, 14) in the co-planar conductor structure (10) is formed to be individually free in space and resilient in relation to the dielectric (28) acting as its mounting, a respective gap (16) being formed between each pair of conductors (12, 14) in the co-planar conductor structure (10) from the co-axial cable end (18) to the contact end (20) in such a way that a constant characteristic impedance is obtained from the co-axial cable end (18) to the contact end (20).
2. Measuring probe (100, 200, 300) according to claim 1, characterized in that the respective gap (16) is made wider in the region of the dielectric (28) than in the region of the co-planar conductor structure (10) where there is no dielectric (28).
3. Measuring probe (100, 200, 300) according to either of claims 1 and 2, characterised in that the dielectric is in the form of at least one block of quartz (28).
4. Measuring probe (100, 200, 300) according to at least one of the foregoing claims, characterised in that the dielectric (28) has, on a side where it is connected to the co-planar conductor structure (10), a metal coating which substantially coincides in shape with the latter.
5. Measuring probe (200) according to at least one of the foregoing claims, characterised in that the dielectric (28) is metallised over its full area on a side remote from the co-planar conductor structure.

ART 34 AMDT

6. Measuring probe according to at least one foregoing claims, characterised in that a planar circuit and in particular an electrical or electronic, i.e. active, circuit or at least one active circuit element is arranged at the co-axial cable end (18).

(12) NACH DEM VERTRAG ÜBER DIE INTERNATIONALE ZUSAMMENARBEIT AUF DEM GEBIET DES PATENTWESENS (PCT) VERÖFFENTLICHTE INTERNATIONALE ANMELDUNG

(19) Weltorganisation für geistiges Eigentum
Internationales Büro



(43) Internationales Veröffentlichungsdatum
29. März 2001 (29.03.2001)

PCT

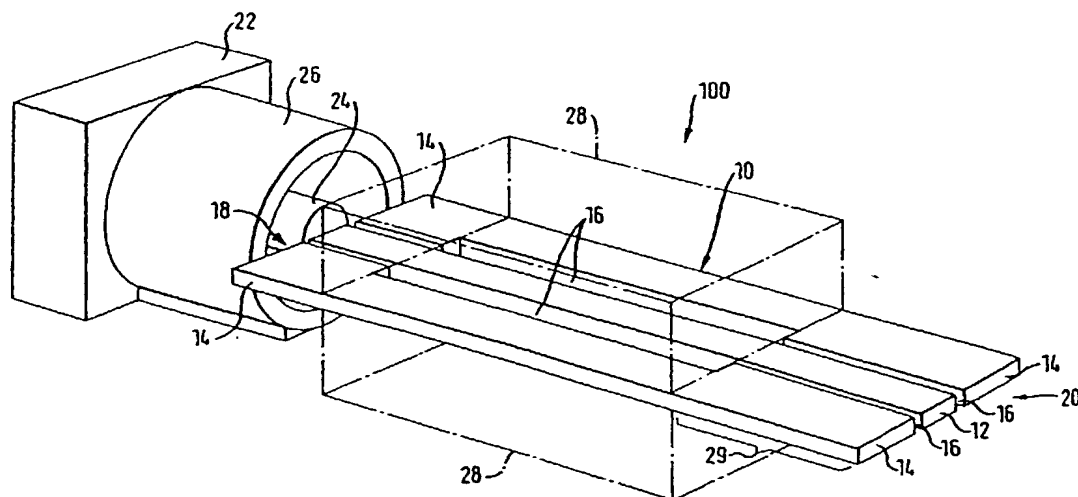
(10) Internationale Veröffentlichungsnummer
WO 01/22097 A1

- (51) Internationale Patentklassifikation⁷: G01R 1/067
- (21) Internationales Aktenzeichen: PCT/DE00/03231
- (22) Internationales Anmeldedatum:
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- (25) Einreichungssprache: Deutsch
- (26) Veröffentlichungssprache: Deutsch
- (30) Angaben zur Priorität:
199 45 178.8 21. September 1999 (21.09.1999) DE
- (71) Anmelder (für alle Bestimmungsstaaten mit Ausnahme von US): ROSENBERGER HOCHFREQUENZTECHNIK GMBH & CO. [DE/DE]; Hauptstrasse 1, 83413 Fridolfing (DE).
- (72) Erfinder; und
(75) Erfinder/Anmelder (nur für US): WOLLITZER, Michael [DE/DE]; Hauptstrasse 1, 83413 Fridolfing (DE).
- (74) Anwalt: ZEITLER, Giselher; Zeitler & Dickel, Herrstrasse 13, 80539 München (DE).
- (81) Bestimmungsstaaten (national): CA, CN, JP, US.
- (84) Bestimmungsstaaten (regional): europäisches Patent (AT, BE, CH, CY, DE, DK, ES, FI, FR, GB, GR, IE, IT, LU, MC, NL, PT, SE).
- Veröffentlicht:
— Mit internationalem Recherchenbericht.
— Vor Ablauf der für Änderungen der Ansprüche geltenden Frist; Veröffentlichung wird wiederholt, falls Änderungen eintreffen.

[Fortsetzung auf der nächsten Seite]

(54) Title: MEASURING PROBE FOR MEASURING HIGH FREQUENCIES AND A METHOD FOR PRODUCING THE SAME

(54) Bezeichnung: MESSSPITZE ZUR HOCHFREQUENZMESSUNG UND VERFAHREN ZU DEREN HERSTELLUNG



(57) Abstract: The invention relates to a measuring probe (100) for measuring high frequencies, comprising a contact end (20) for contacting planar structures and a coaxial-cable end (18) for connecting to a coaxial cable (22), whereby a coplanar conductor structure (10) consisting of at least two conductors (12, 14) is located between the contact end (20) and the coaxial-cable end (18). A dielectric (28) which supports the coplanar conductor structure (10) is provided on at least one side, in particular both sides of the coplanar conductor structure (10) which extends over a predetermined section between the coaxial-cable end (18) and the contact end (20). Between the dielectric (28) and the contact end (20), the measuring probe (100) is configured in such a way, that the conductors (12, 14) of the coplanar conductor structure (10) are held freely in space and are mounted in an elastic manner in relation to the supporting dielectric (28).

[Fortsetzung auf der nächsten Seite]

WO 01/22097 A1

FIG. 1

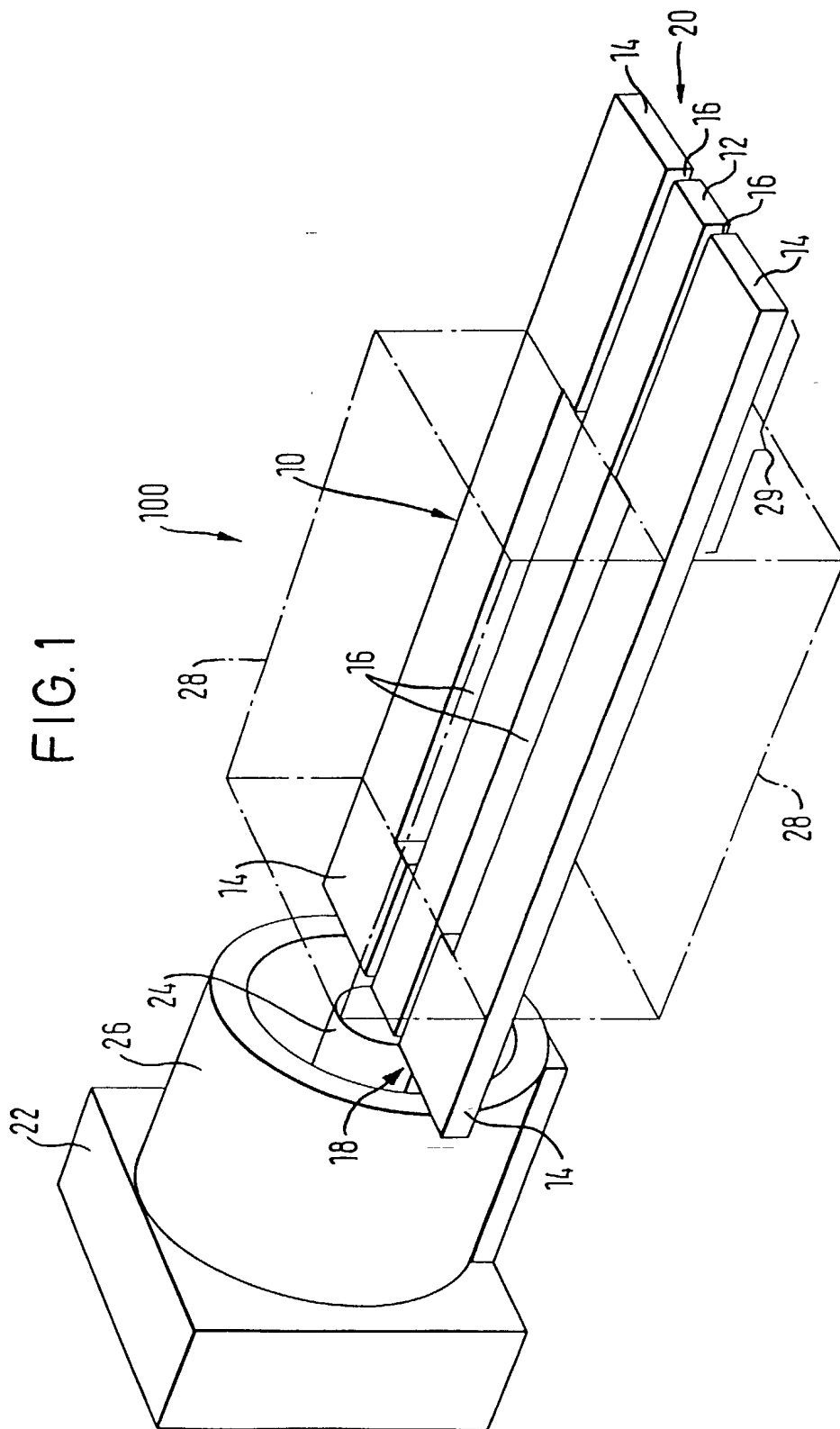


FIG. 2

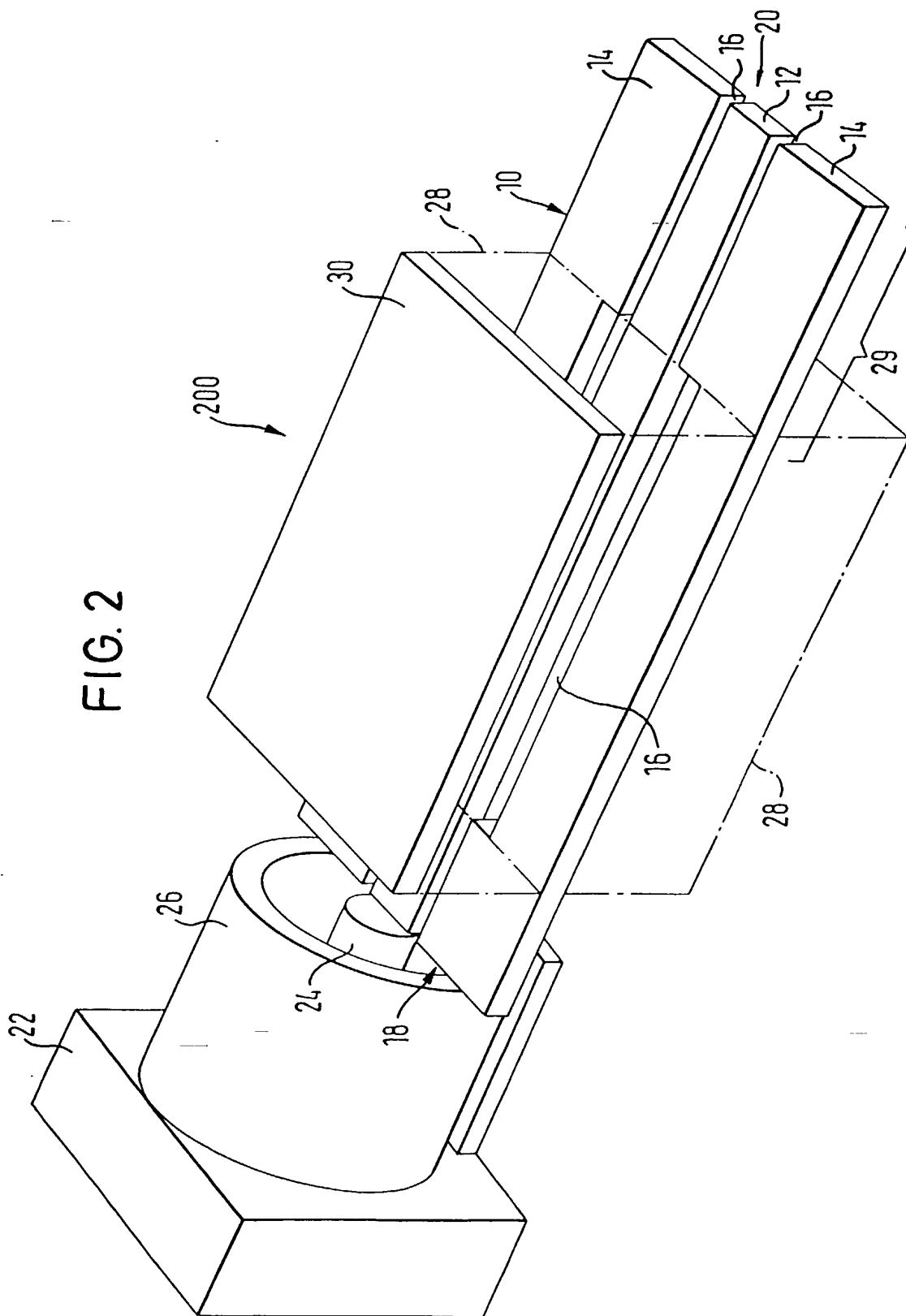


FIG. 4

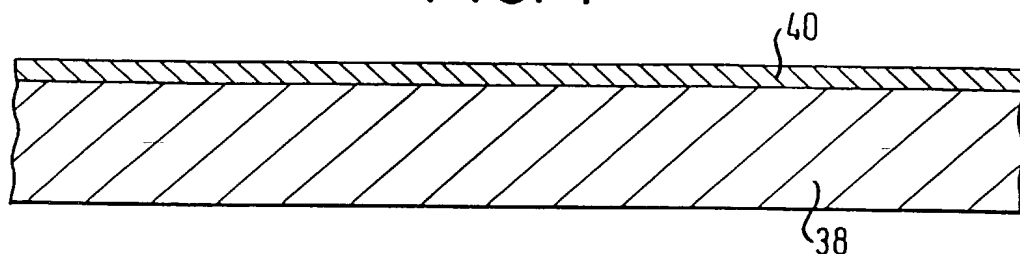


FIG. 5

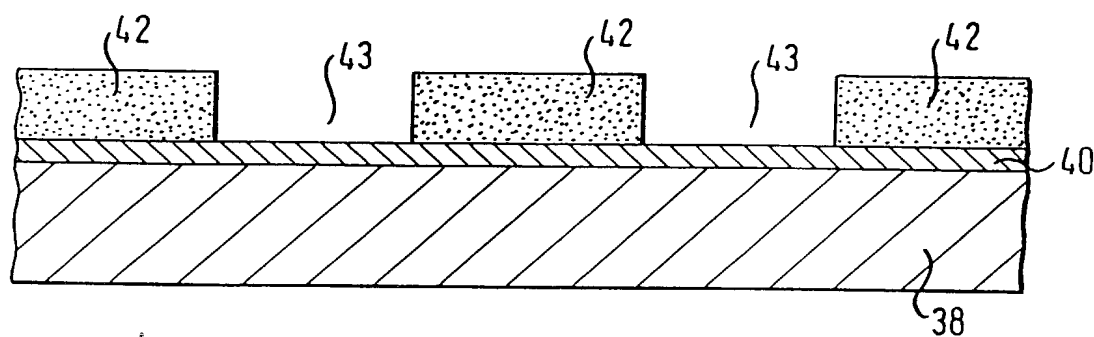


FIG. 6

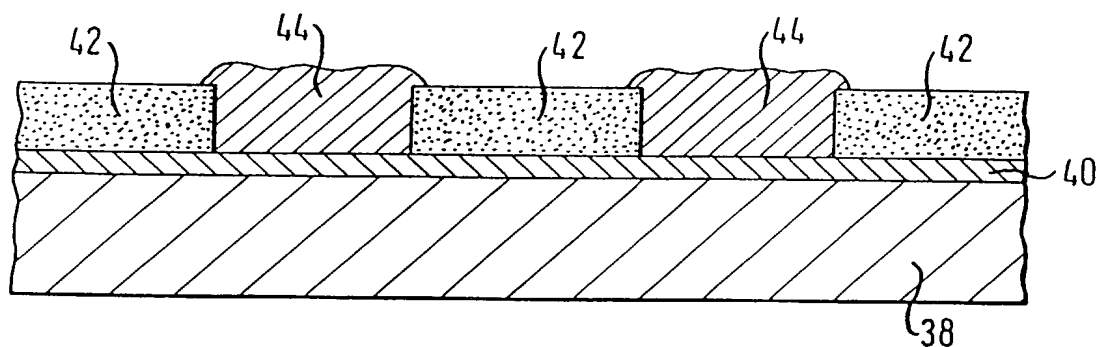


FIG. 7

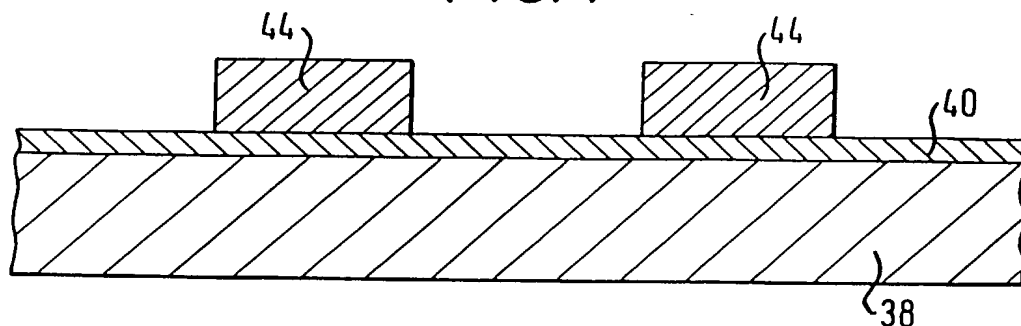
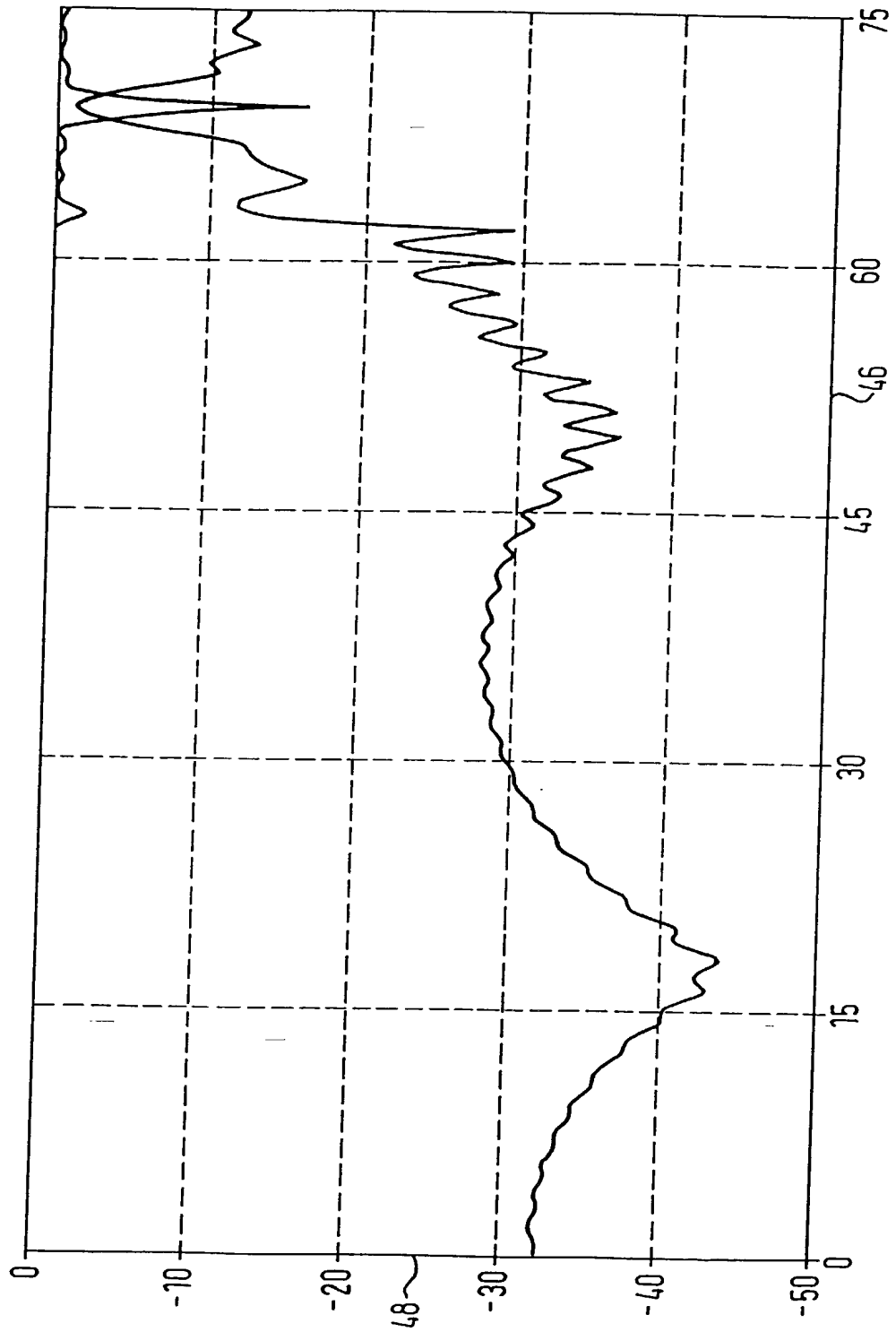


FIG. 8



DECLARATION FOR PATENT APPLICATION AND APPOINTMENT OF ATTORNEY

As a below-named inventor, I hereby declare that my residence, post office address and citizenship are as stated below next to my name; I believe that I am the original, first and sole inventor (if only one name is listed below) or an original, first and joint inventor (if plural names are listed below) of the subject matter which is claimed and for which a patent is sought on the invention (Design, if applicable) entitled: **MEASURING PROBE FOR MEASURING HIGH FREQUENCIES AND METHOD OF PRODUCING THE SAME**

the specification of which (check one):

- ☐ is attached hereto.
- ☒ was filed on March 21, 2002 as Application Serial No. 10/088,591
- ☐ was filed on September 18, 2000 as International Application (PCT) No. PCT/DE00/03231, and was amended on November 7, 2001 (if applicable)

I hereby state that I have reviewed and understand the contents of the above-identified specification, including the claims, as amended by any amendment(s) referred to above. I acknowledge the duty to disclose all information which is material to the examination of this application in accordance with *Title 37, Code of Federal Regulations, § 1.56*. I hereby claim foreign priority benefits under *Title 35, United States Code § 119* of any foreign application(s) for patent or inventor's certificate listed below and have also identified below any foreign application for patent or inventor's certificate having a filing date before that of the application on which the priority is claimed.

PRIOR FOREIGN APPLICATION(S)

NUMBER	COUNTRY	DAY/MONTH/YEAR FILED	PRIORITY CLAIMED
199 45 178.8	Germany	21/09/1999	<input checked="" type="checkbox"/> Yes <input type="checkbox"/> No
			<input type="checkbox"/> Yes <input type="checkbox"/> No

I hereby claim the benefit under *Title 35, United States Code, § 120* of any United States application(s) or PCT international application(s) designating The United States of America listed below and, insofar as the subject matter of each of the claims of this application is not disclosed in that/those prior application(s) in the manner provided by the first paragraph of *Title 35, United States Code, § 112, 1* acknowledge the duty to disclose material information as defined in *Title 37, Code of Federal Regulations, § 1.56* which occurred between the filing date of the prior application(s) and the national or PCT international filing date of this application:

APPLICATION NUMBER	FILING DATE	STATUS (Patented, Pending or Abandoned)

I hereby declare that all statements made herein of my own knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine, or imprisonment, or both, under *Section 1001 of Title 18 of the United States Code*, and that such willful false statements may jeopardize the validity of the application or any patent issued thereon.

POWER OF ATTORNEY: I (We) hereby appoint as my (our) attorneys, with full powers of substitution and revocation, to prosecute this application and transact all business in the Patent and Trademark Office connected therewith: Allan M. Lowe, Registration Number 19,641; Benjamin J. Hauptman, Registration Number 29,310; Michael G. Gilman, Registration Number 19,114; Kenneth M. Berner, Registration Number 37,093; and Randy A. Noranbrock, Registration Number 42,940.

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I hereby authorize the U.S. attorneys and agents named herein to accept and following instructions from Zeitler Dickel Kandlbinder as to any actions to be taken in the U.S. Patent and Trademark Office regarding this application without direct communication between the U.S. attorneys and the undersigned. In the event of a change in the person(s) from whom instructions may be taken, the U.S. attorneys will be so notified by the undersigned.

☐ See following page(s) for additional joint inventors.

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